

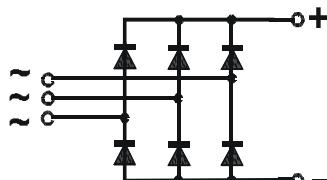
## Three Phase Rectifier Bridge (TRACTION - PAC<sup>TM</sup>)

PSTD 82

$I_{dAV}$  = 88 A  
 $V_{RRM}$  = 800-1800V

Preliminary Data Sheet

| $V_{RSM}$        | $V_{RRM}$        | Type       |
|------------------|------------------|------------|
| $V_{DSM}$<br>(V) | $V_{DRM}$<br>(V) |            |
| 800              | 800              | PSTD 82/08 |
| 1200             | 1200             | PSTD 82/12 |
| 1400             | 1400             | PSTD 82/14 |
| 1600             | 1600             | PSTD 82/16 |
| 1800             | 1800             | PSTD 82/18 |



### Symbol Test Conditions Maximum Ratings

|               |   |              |                      |
|---------------|---|--------------|----------------------|
| $I_{dAVM}$    | $T_C = 110^\circ\text{C}$ , (per module)                      | 88           | A                    |
| $I_{FSM}$     | $T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine | 750          | A                    |
|               | $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine                  | 820          | A                    |
|               | $T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine          | 670          | A                    |
|               | $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine                  | 740          | A                    |
| $\int i^2 dt$ | $T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine | 2800         | $\text{A}^2\text{s}$ |
|               | $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine                  | 2800         | $\text{A}^2\text{s}$ |
|               | $T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine          | 2250         | $\text{A}^2\text{s}$ |
|               | $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine                  | 2250         | $\text{A}^2\text{s}$ |
| $T_{VJ}$      |   | -40... + 150 | $^\circ\text{C}$     |
| $T_{VJM}$     |   | 150          | $^\circ\text{C}$     |
| $T_{stg}$     |   | -40... + 125 | $^\circ\text{C}$     |
| $V_{ISOL}$    | 50/60 Hz, RMS $t = 1 \text{ min}$                             | 2500         | V~                   |
|               | $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$                | 3000         | V~                   |
| $M_d$         | Mounting torque (M5)  | 5.0/44       | Nm/lb.in.            |
|               | Terminal connection torque (M5)                               | 3.0/26       | Nm/lb.in.            |
| <b>Weight</b> | typ.  | 170          | g                    |

| Symbol     | Test Conditions                                     | Characteristic Value |       |                  |
|------------|---|----------------------|-------|------------------|
| $I_R$      | $V_R = V_{RRM}$ , $T_{VJ} = 25^\circ\text{C}$       | $\leq$               | 0.3   | mA               |
|            | $V_R = V_{RRM}$ , $T_{VJ} = T_{VJM}$                | $\leq$               | 5     | mA               |
| $V_F$      | $I_F = 150 \text{ A}$ , $T_{VJ} = 25^\circ\text{C}$ | $\leq$               | 1.6   | V                |
| $V_{TO}$   | For power-loss calculations only                    |                      | 0.8   | V                |
| $r_T$      |   |                      | 5     | $\text{m}\Omega$ |
| $R_{thJC}$ | per diode; DC current                               |                      | 1.1   | K/W              |
|            | per module  |                      | 0.183 | K/W              |
| $R_{thJK}$ | per diode; DC current                               |                      | 1.52  | K/W              |
|            | per module  |                      | 0.253 | K/W              |
| $d_s$      | Creeping distance on surface                        |                      | 10.0  | mm               |
| $d_A$      | Creeping distance in air                            |                      | 9.4   | mm               |
| $a$        | Max. allowable acceleration                         |                      | 50    | $\text{m/s}^2$   |

Data according to IEC 60747 refer to a single diode unless otherwise stated

### Features

- Package with screw terminals
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop

### Applications

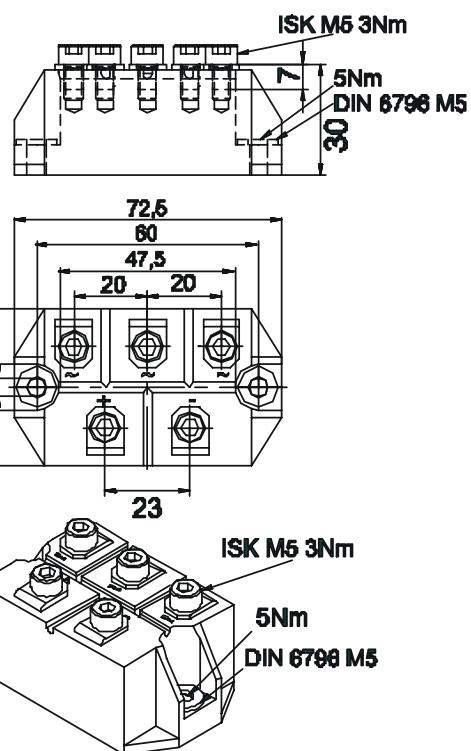
- Supplies for DC power equipment
- Input rectifier for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability

### Package style and outline

Dimensions in mm (1mm = 0.0394")



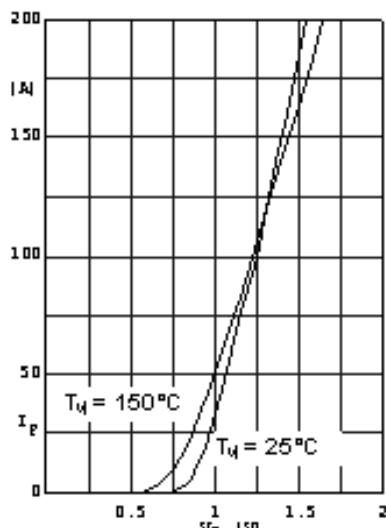


Fig. 1 Forward current versus voltage drop per diode

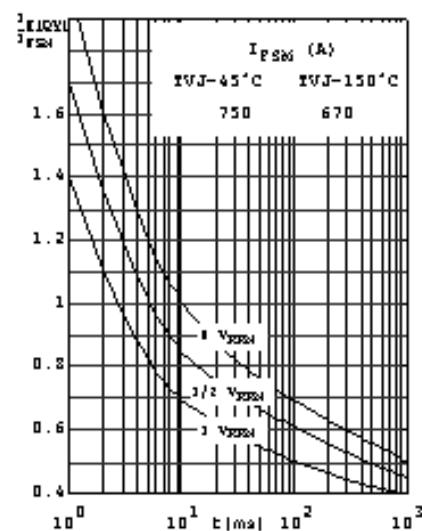


Fig. 2 Surge overload current per diode  $I_{FSM}$ : Crest value.  $t$ : duration

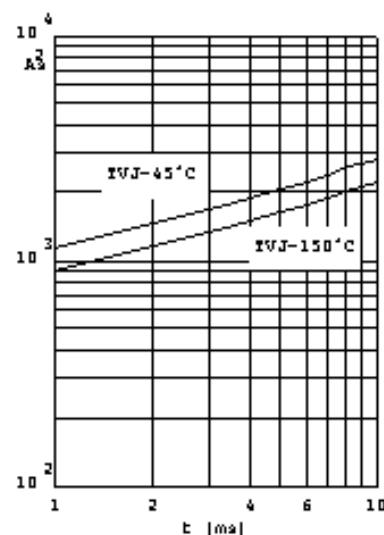


Fig. 3  $\int i^2 dt$  versus time (1-10ms) per diode (or thyristor)

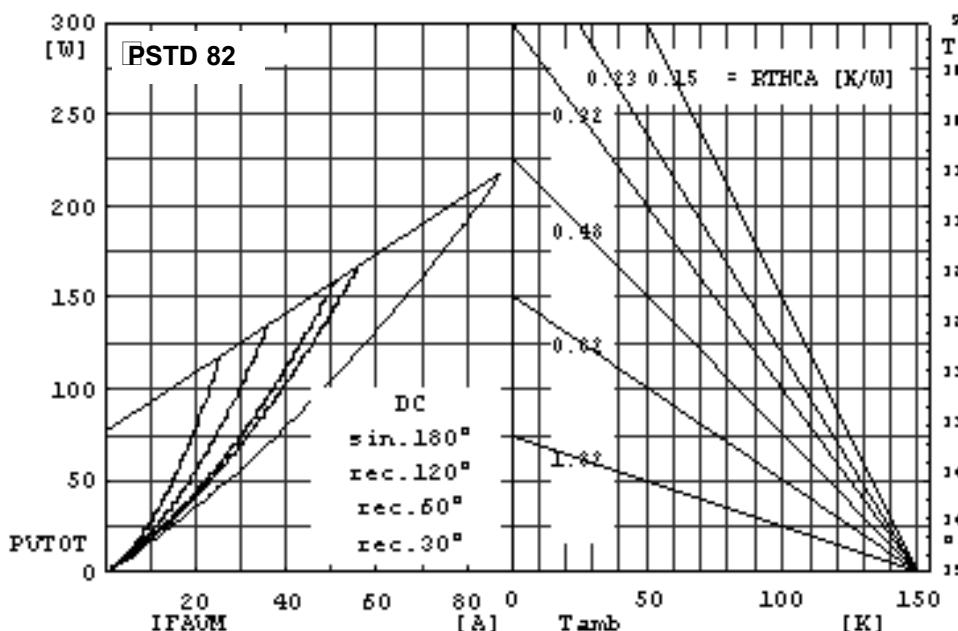


Fig. 4 Power dissipation versus direct output current and ambient temperature

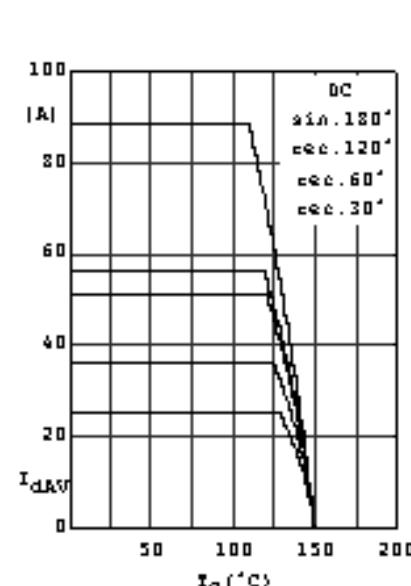


Fig. 5 Maximum forward current at case temperature

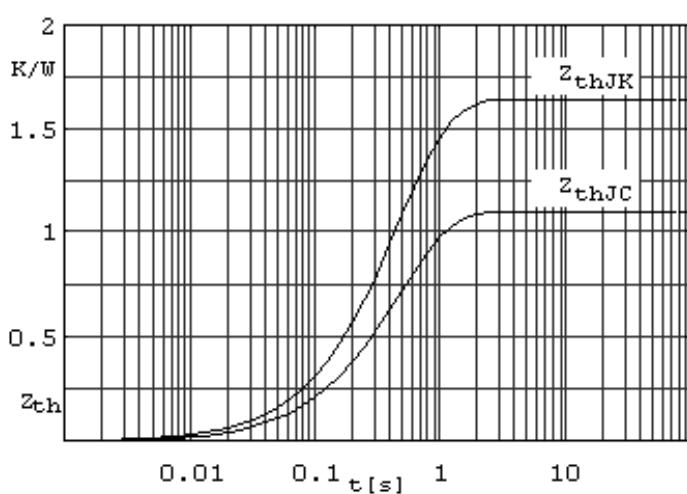


Fig. 6 Transient thermal impedance per diode (or thyristor), calculated